

Superfluid density tensor in unconventional superconductors

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We consider the superfluid density tensor ρ_s for two unconventional spin-triplet gaps: an A phase and a polar phase. We pay particular attention to the effect of impurity scattering and how such scattering influences the anisotropy of ρ_s .

I. INTRODUCTION

The current-carrying state in unconventional superconductors has recently been the subject of experimental^{1,2} and theoretical¹⁻⁵ investigation. One particularly important quantity for theoreticians to calculate is the superfluid density tensor, ρ_s , since it is directly related to the measurable magnetic penetration depth.¹⁻³

The theory of ρ_s is discussed in Refs. 1, 2, and 3. In this work we discuss ρ_s using the quasiclassical⁶ theory of superconductivity, paying particular attention to the effect of nonmagnetic impurities. As already noted,² for a spherical Fermi surface impurities have the interesting effect of enhancing the anisotropy of ρ_s . A simple way to understand this enhancement is to realize that impurities dramatically increase the number of low-energy quasiparticle states in the vicinity of gap nodes on the Fermi surface.⁷ This serves to decrease ρ_s proportionately more in the direction of such nodes than in the direction perpendicular to the nodes.

We consider, as does Ref. 2, two types of gap: an A phase type with two point nodes, and a polar phase gap with a line of nodes. We consider a metal with a spherical Fermi surface in the normal state, with a concentration c of impurities.

In Sec. II we use the quasiclassical theory to derive some general expressions for ρ_s . In Secs. III and IV we examine in more detail two limits: the $T=0$ limit and the Ginzburg-Landau regime near T_c .

II. GENERAL RESULTS

To do our calculations we use the same quasiclassical formalism⁶ used in our previous work.^{4,5} We include scattering from randomly placed impurities of concentration c ; for simplicity we take the scattering potential to be purely s wave and of strength v . We solve for the gauge transformed propagator $\bar{g}(\mathbf{k}, \epsilon)$, which is a 2×2 matrix in the particle-hole space. To compute the current \mathbf{J} we need the $\hat{\tau}_3$ component of the propagator, g_3 . For the A -phase gap,

$$\Delta_{\alpha\beta}(\hat{\mathbf{k}}) = \delta_{\alpha\beta} \Delta_0 (\hat{\mathbf{x}} + i\hat{\mathbf{y}}) \cdot \hat{\mathbf{k}}, \quad (1)$$

we find

$$g_3 = \frac{-\pi i(\epsilon + iq + ia_3)}{[(\epsilon + iq + ia_3)^2 + (\Delta_0 \hat{\mathbf{k}} \cdot \hat{\mathbf{y}} - ia_1)^2 + (\Delta_0 \hat{\mathbf{k}} \cdot \hat{\mathbf{x}} - ia_2)^2]^{1/2}}.$$

For a polar gap,

$$\Delta_{\alpha\beta}(\hat{\mathbf{k}}) = \delta_{\alpha\beta} \Delta_0 \hat{\mathbf{k}} \cdot \hat{\mathbf{z}}, \quad (3)$$

we find

$$g_3 = \frac{-\pi i(\epsilon + iq + ib_3)}{[(\epsilon + iq + ib_3)^2 + (\Delta_0 \hat{\mathbf{k}} \cdot \hat{\mathbf{z}} - ib_2)^2]^{1/2}}. \quad (4)$$

In these equations, $q = p_f \hat{\mathbf{k}} \cdot \mathbf{v}_s$, and Δ_0 is the gap amplitude with impurity scattering fully taken into account. To first order in \mathbf{v}_s , the amplitude and structure of the gap are unaffected by the superflow, and to compute ρ_s we need g_3 only to first order in \mathbf{v}_s .

The quantities $a_i(\epsilon)$ (A phase) and $b_i(\epsilon)$ (polar phase) are given by ct_i , where t_i is the $\hat{\tau}_i$ component of the impurity t matrix. The t matrix is computed from

$$\bar{t}(\epsilon) = v + N_0 v \int \frac{d\hat{\mathbf{k}}}{4\pi} \bar{g}(\hat{\mathbf{k}}, \epsilon) \bar{t}(\epsilon), \quad (5)$$

as in our previous work,^{4,5} we used the full impurity averaged \bar{g} in (5), so that our results are not limited to the dilute regime. The functions $a_3(\epsilon)$ and $b_3(\epsilon)$ may be evaluated at $\mathbf{v}_s = 0$, while $a_1(\epsilon)$, $a_2(\epsilon)$, and $b_2(\epsilon)$, being odd function of \mathbf{v}_s , are evaluated to first order in \mathbf{v}_s . Hence we write $a_1(\epsilon) = \alpha_1(\epsilon) \mathbf{v}_s \cdot \hat{\mathbf{y}}$, $a_2(\epsilon) = \alpha_2(\epsilon) \mathbf{v}_s \cdot \hat{\mathbf{x}}$, and $b_2(\epsilon) = \beta_2(\epsilon) \mathbf{v}_s \cdot \hat{\mathbf{z}}$; it is straightforward to check that a_1 , a_2 , and b_2 are proportional, respectively, to $\mathbf{v}_s \cdot \hat{\mathbf{y}}$, $\mathbf{v}_s \cdot \hat{\mathbf{x}}$, and $\mathbf{v}_s \cdot \hat{\mathbf{z}}$.

We now expand g_3 to first order in \mathbf{v}_s , and use the result to compute \mathbf{J} . We then obtain, for the A phase,

$$\rho_{ij}^s = 2N_0 v_f \Delta_0 \pi T \sum_{\epsilon} \int \frac{d\hat{\mathbf{k}}}{4\pi} \Delta_0 \rho_f \hat{\mathbf{k}}_i \hat{\mathbf{k}}_j [1 - (\hat{\mathbf{k}} \cdot \hat{\mathbf{z}})^2] + (\epsilon + ia_3) [\alpha_1 (\hat{\mathbf{k}} \cdot \hat{\mathbf{y}})^2 \hat{\mathbf{y}}_i \hat{\mathbf{y}}_j + \alpha_2 (\hat{\mathbf{k}} \cdot \hat{\mathbf{x}})^2 \hat{\mathbf{x}}_i \hat{\mathbf{x}}_j] \\ \{(\epsilon + ia_3)^2 + \Delta_0^2 [1 - (\hat{\mathbf{k}} \cdot \hat{\mathbf{z}})^2]\}^{3/2} \quad (6)$$

and, for the polar phase,

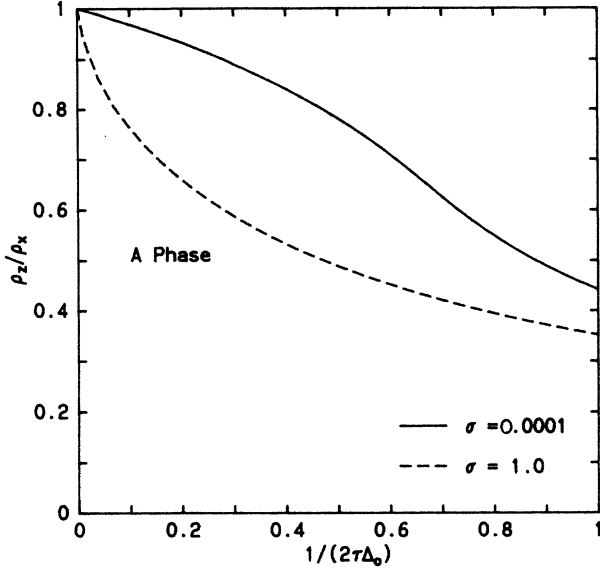


FIG. 1. Plot of ρ_z^s / ρ_{xx}^s versus $1/(2\tau\Delta_0)$ for the *A* phase at $T=0$. The solid line is for the Born limit ($\sigma=0.0001$), while the dashed line is for the unitarity limit ($\sigma=1.0$).

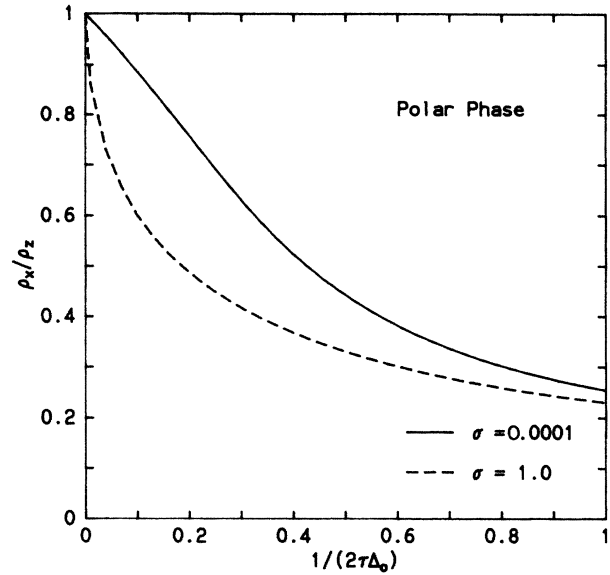


FIG. 2. Plot of $\rho_{xx}^s / \rho_{zz}^s$ versus $1/(2\tau\Delta_0)$ for the polar phase at $T=0$. Born and unitarity limits are shown, as in Fig. 1.

$$\rho_{ij}^s = 2N_0 v_f \Delta_0 \pi T \sum_{\epsilon} \int \frac{d\hat{\mathbf{k}}}{4\pi} \frac{\Delta_0 p_f (\hat{\mathbf{k}} \cdot \hat{\mathbf{z}})^2 \hat{\mathbf{k}}_i \hat{\mathbf{k}}_j + \beta_2 (\epsilon + ib_3) (\hat{\mathbf{k}} \cdot \hat{\mathbf{z}})^2 \hat{\mathbf{z}}_i \hat{\mathbf{z}}_j}{[(\epsilon + ib_3)^2 + \Delta_0^2 (\hat{\mathbf{k}} \cdot \hat{\mathbf{z}})^2]^{3/2}}. \quad (7)$$

Results (6) and (7) are valid for any temperature T . We now discuss two limiting cases.

III. $T=0$ CASE

Firstly, we consider $T=0$. We must then numerically solve for the functions $\alpha_1(\epsilon)$, $\alpha_2(\epsilon)$, $a_3(\epsilon)$, $\beta_2(\epsilon)$, and $b_3(\epsilon)$. In Figs. 1 and 2 we show results which illustrate the anisotropic behavior of ρ_s at $T=0$. For the *A* phase we plot ρ_z^s / ρ_{xx}^s as a function of $1/(2\tau\Delta_0)$, while for the polar phase we plot $\rho_{xx}^s / \rho_{zz}^s$. Here, $1/\tau$ is the normal state impurity scattering rate, and Δ_0 is the order parameter magnitude with impurity scattering taken into account. Hence, the parameter $1/(2\tau\Delta_0)$ ranges from zero to infinity as the impurity concentration increases.

The parameter σ is defined as

$$\sigma = \frac{(N_0 v_f \pi)^2}{1 + (N_0 v_f \pi)^2}.$$

We show results for $\sigma=0.0001$ (Born limit) and $\sigma=0.9999$ (unitarity limit). In the Born limit, the *A* phase becomes gapless when $1/(2\tau\Delta_0)=2/\pi$, whereas in the unitarity limit the *A* phase is gapless for any nonzero value of $1/(2\tau\Delta_0)$.⁷ The polar phase is gapless whenever $1/\tau$ is nonzero, regardless of the value of σ .⁷

Figures 3 and 4 show how the ratios ρ_{xx}^s / ρ , ρ_{zz}^s / ρ decrease from unity as impurities are added.

IV. GINZBURG-LANDAU LIMIT

In this limit, we work to lowest order in Δ_0^2 , and more analytic progress is possible. We expand (6) and (7) to first order in Δ_0^2 ; we note that $a_3(\epsilon)$ and $b_3(\epsilon)$ can then be evaluated in the normal state, where we have

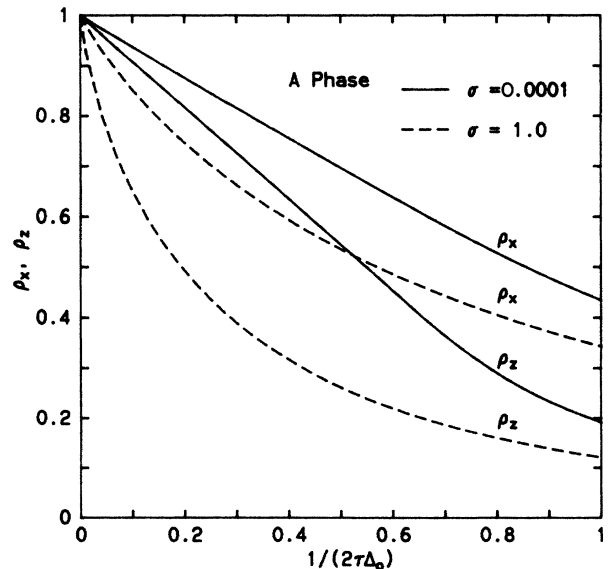


FIG. 3. Plot of ρ_{xx}^s / ρ and ρ_{zz}^s / ρ versus $1/(2\tau\Delta_0)$ for the *A* phase at $T=0$. Born ($\sigma=0.0001$) and unitarity ($\sigma=1.0$) limits are shown.

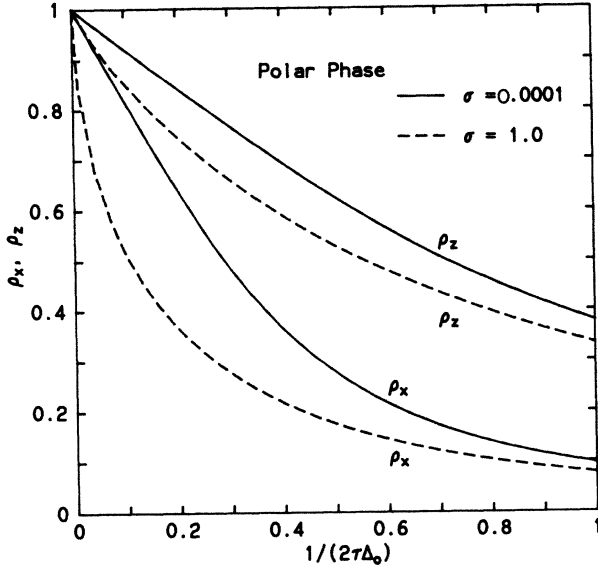


FIG. 4. Plot of ρ_{xx}^s/ρ and ρ_{zz}^s/ρ versus $1/(2\tau\Delta_0)$ for the polar phase at $T=0$. Born ($\sigma=0.0001$) and unitarity ($\sigma=1.0$) limits are shown.

$$ia_3 = ib_3 = \frac{N_0 v^2 \pi c \operatorname{sgn}(\epsilon)}{1 + (N_0 v \pi)^2} \equiv \frac{1}{2\tau} \operatorname{sgn}(\epsilon). \quad (8)$$

The functions α_1 , α_2 , and β_2 are evaluated to lowest order in Δ_0 . The final results for ρ_s are as follows.

A phase:

$$\rho_{ij}^s = \frac{N_0 v_f p_f \Delta_0^2}{15\pi^2 T_c^2} [\hat{z}_i \hat{z}_j S_3 + (\hat{x}_i \hat{x}_j + \hat{y}_i \hat{y}_j)(2S_3 + \frac{5}{6}wS_5)]. \quad (9)$$

Polar phase:

$$\rho_{ij}^s = \frac{N_0 v_f p_f \Delta_0^2}{2\pi^2 T_c^2} [\hat{z}_i \hat{z}_j (\frac{1}{5}S_3 + \frac{1}{3}wS_5) + \frac{1}{15}(\hat{x}_i \hat{x}_j + \hat{y}_i \hat{y}_j)S_3]. \quad (10)$$

Here, we define $w \equiv 1/(4\pi\tau T_c)$, and the two functions S_3 and S_5 are defined as

$$S_3 = \sum_{n \geq 0} \frac{1}{(n + \frac{1}{2} + w)^3}, \quad (11)$$

$$S_5 = \sum_{n \geq 0} \frac{1}{(n + \frac{1}{2})(n + \frac{1}{2} + w)^3}. \quad (12)$$

For small w , we have

$$S_3 \approx 7\zeta(3) - \frac{\pi^4}{2}w + \dots, \quad (13)$$

$$S_5 \approx \frac{\pi^4}{6} + \dots, \quad (14)$$

while for large w , we have

$$S_3 \approx \frac{1}{2w^2} - \frac{1}{8w^4} + \dots, \quad (15)$$

$$S_5 \approx \frac{\ln(w)}{w^3} - \frac{1}{w^3}[\psi(\frac{1}{2}) + \frac{3}{2}] + \frac{1}{4w^5} + \dots. \quad (16)$$

Here $\psi(x)$ is the digamma function. So, if we examine the anisotropy ratios, we find, for the *A* phase,

$$\rho_{xx}^s/\rho_{zz}^s \approx 2 + 1.608w + \dots, \quad w \ll 1 \quad (17)$$

$$\rho_{xx}^s/\rho_{zz}^s \approx \frac{5}{3}\ln(w) - \frac{1}{2} - \frac{5}{3}\psi(\frac{1}{2}) + \dots, \quad w \gg 1 \quad (18)$$

and, for the polar phase,

$$\rho_{zz}^s/\rho_{xx}^s \approx 3 + 3.215w + \dots, \quad w \ll 1 \quad (19)$$

$$\rho_{zz}^s/\rho_{xx}^s \approx \frac{10}{3}\ln(w) - 2 - \frac{10}{3}\psi(\frac{1}{2}) + \dots, \quad w \gg 1. \quad (20)$$

We note that the anisotropy ratio can be made as large as we want, by increasing w . The quantity w varies from zero to infinity as c increase from zero to the critical concentration which makes T_c vanish.

V. DISCUSSION

Our work, following that of Gross *et al.*,² illustrates how, for a superconductor with an anisotropic gap and a spherical Fermi surface, the presence of impurities can enhance the anisotropy of ρ_s . It is of interest to include the effect of a more realistic Fermi surface, and we hope to turn to this problem in the future. If ρ_s is anisotropic even in the pure limit, because of an anisotropic Fermi surface, the effect of impurities could well be more complicated.

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